

INFORMATION
DISCLOSURE
CITATION FORM FOR
PATENT APPLICATION
(FORM PTO - 1449)

Docket No.: 3536 C02

Serial No.: 09/775,295

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

Group: ~~1763~~

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U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date
gag	4,438,723✓	03-27-84	CANNELLA ET AL.			
	4,440,107✓	04-03-84	DOEHLER ET AL.			
	4,483,737✓	11-20-84	MANTEI			
	4,810,935✓	03-07-89	BOSWELL			
	4,842,707✓	06-27-89	KINOSHITA			
	4,990,229✓	02-05-91	CAMPBELL ET AL.			
	4,993,361✓	02-19-91	UNVALA			
	5,091,049✓	02-25-92	CAMPBELL ET AL.			
	5,122,251✓	06-16-92	CAMPBELL ET AL.			
	5,160,398✓	11-03-92	YANAGIDA			
	5,178,739✓	01-12-93	BARNES ET AL.			
	5,224,441✓	07-06-93	FELTS ET AL.			
gag	5,346,579✓	09-13-94	COOK ET AL.			

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	
gag	EP 0 173 583✓	05.03.86	EUROPE	KIM KUYNGSHIK ET AL.	1763
	EP 0 651 425✓	03.05.95	EUROPE	ROBERT CHAPMAN	1763
	EP 0 786 794✓	03.07.97	EUROPE	PETER LOEWENHARDT ET AL.	1763
gag	7-22389✓	24.01.95	JAPAN	YUTAKA KAKCHI ET AL.	1763

Initials

Other Documents (Title, Author, Date, Pages, Etc., if known)

Quick, A.K., Chen, R.T.S., and Hershkowitz, N., "Etch rate and plasma density radial uniformity measurements in a cusped field helicon plasma etcher," *J. Vac. Sci. Technol.*, Vol. 14, No. 3, May/June 1996, pp. 1041-1045.

Examiner's Signature:

George Gaudreau

Date Considered:

9-031

Initial if reference was considered, whether or not citation with MPEP. Mark through citation if not considered. Include a copy of this citation form with your next correspondence to the Applicant(s).

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Docket No.: 3536 C02

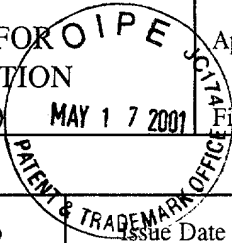
Serial No.: 09/775,295

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01

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U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Section	Filing Date
gag	5,401,351✓	03-28-95	SAMUKAWA			
	5,421,891✓	06-06-95	CAMPBELL ET AL.			
	5,429,070✓	07-04-95	CAMPBELL ET AL.			
	5,484,485✓	01-16-96	CHAPMAN			
	5,556,501✓	09-17-96	COLLINS ET AL.			
	5,662,819✓	09-02-97	KADOMURA			
	6,030,486✓	02-29-00	LOEWENHARDT, ET AL.			
gag	6,054,013✓	04-25-00	COLLINS, ET AL.			

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)
gag	U.S. Patent Application Serial No. 09/263,001, Filed March 5, 1999, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.
	U.S. Patent Application Serial No. 09/521,799, Filed March 9, 2000, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Gerald Yin, et al.
gag	U.S. Patent Application Serial No. 09/773, 409, Filed January 31, 2001, entitled, "Magnetically Enhanced Inductively Coupled Plasma Reactor with Magnetically Confined Plasma," by Peter Loewenhardt, et al.

Examiner's Signature:

George Gouldman

Date Considered:

9-031

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INFORMATION
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Docket No.: 3536 C02 Serial No.: 09/775,293

Applicant(s): JAMES CARDUCCI, ET AL.

Filing Date: 01-31-01 Group: ~~1763~~

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U. S. PATENTS

Initials	Patent No	Issue Date	Name	Class	Subclass	Filing Date
GAG	6,074,518 ✓	06-13-00	IMAFUKU ET AL.	156	345	01-04-99
GAG	6,189,484 ✓	02-20-01	YIN ET AL.	118	723	03-05-99

FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation? (Yes/No/n/a)

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)

Examiner's Signature:

George Goudreau

Date Considered:

9-03'

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Applicant(s): JAMES CARDUCCI, ET AL.

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U. S. PATENTS

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FOREIGN PATENT DOCUMENTS

Initials	Document Number	Date	Country	Name	Translation (Yes/No/NA)
gag	HEI 8-264515	11.10.96	JAPAN	MITSUYOSHI IMAFUKU ET AL.	NA

Initials	Other Documents (Title, Author, Date, Pages, Etc., if known)

Examiner's Signature:

George Gaudreau

Date Considered:

9-031

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